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DT01 Rec'd PCT/PT 21 OCT 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Okuyama et al.
Intl. Appl. No.: PCT/JP04/001952
Intl. Filing Date: February 19, 2004
Title: SEMICONDUCTOR LIGHT EMITTING ELEMENT,
MANUFACTURING METHOD THEREOF, INTEGRATED
SEMICONDUCTOR LIGHT EMITTING DEVICE,
MANUFACTURING METHOD THEREOF, IMAGE DISPLAY
DEVICE, MANUFACTURING METHOD THEREOF,
ILLUMINATING DEVICE AND MANUFACTURING METHOD
THEREOF
Docket No.: 112857-534

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 37 C.F.R. 1.97, and 37 C.F.R. 1.98, Applicants request that a citation and examination of the references cited below, and on the attached PTO-1449 form, copies of which are enclosed, be made during the course of examination of the above-identified application for United States patent.

FOREIGN PATENT DOCUMENTS

<u>Document No.</u>	<u>Date</u>	<u>Country</u>
06-045648	02-18-1994	Japan
09-129974	05-16-1997	Japan
11-026883	01-29-1999	Japan
2002-100805	04-05-2002	Japan
2002-261327	09-13-2002	Japan

OTHER DOCUMENTS

Tachibana, K. et al., "Selective growth of InGaN quantum dot structures and their microphotoluminescence at room temperature," Applied Physics Letters, 29 May, 2000, Vol. 76, No. 22, pp. 3212-3214.

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Applicants look forward to early and favorable consideration of this matter.

Respectfully submitted,

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BY 

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INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary) PTO Form 1449	Atty Docket No. 112857-534	Application No. 1047512131
	Applicant Okuyama et al.	
	Filing Date October 21, 2004	Group Unknown

U.S. PATENT DOCUMENTS							
Examiner's Initials		Document Number	Publication Date	Inventor	Class	Subclass	Filing Date If Appropriate

FOREIGN PATENT DOCUMENTS								
Examiner's Initials		Document Number	Publication Date	Country	Class	Subclass	Translation	
							Yes	No
		06-045648	02-18-1994	Japan				
		09-129974	05-16-1997	Japan				
		11-026883	01-29-1999	Japan				
		2002-100805	04-05-2002	Japan				
		2002-261327	09-13-2002	Japan				

Examiner's Initials		OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)
		Tachibana, K. et al., "Selective growth of InGaN quantum dot structures and their microphotoluminescence at room temperature," Applied Physics Letters, 29 May, 2000, Vol. 76, No. 22, pp. 3212-3214.

Examiner:	Date Considered:
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	